

Technical Data Sheet

ACS Material Graphene Dispersion in NMP

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1. Preparation Method

Electrochemical Cleavage Method

2. Characterizations

BET surface area (m²/g):	650-750
Conductivity (S/m):	500-700
Layers:	1-5 atomic layer graphene nanosheets
Lateral size (µm):	0.5-5
Oxygen (wt%):	7-7.5

3. Application Fields

- 1) XPS patterns of Single Layer Graphene
- 2) Catalyst
- 3) Supercapacitors
- 4) Solar energy
- 5) Graphene semiconductor chips
- 6) Conductive graphene film
- 7) Graphene computer memory
- 8) Biomaterials
- 9) Transparent conductive coatings

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